30 April 2025

**Product data sheet** 

## 1. General description

The NSF040120D7A1 is a Silicon Carbide based 1200 V power MOSFET in a well-established 7-pin TO-263 plastic package for surface mounting PCB technology. The excellent  $R_{DSon}$  temperature stability combined with its fast switching speed makes it a product of choice in high power and high voltage industrial applications like E-vehicle charging infrastructure, photovoltaic inverters and motor drives.

### 2. Features and benefits

- Excellent R<sub>DSon</sub> temperature stability
- Very low switching losses
- Fast reverse recovery
- · Fast switching speed
- Temperature independent turn-off switching losses
- · Very fast and robust intrinsic body diode
- · Faster commutation and improved switching due to the additional Kelvin source pin

## 3. Applications

- E-vehicle charging infrastructure
- Photovoltaic inverters
- Switch mode power supply
- Uninterruptable power supply
- · Motor drives

### 4. Quick reference data

#### Table 1. Quick reference data

| Symbol            | Parameter                        | Conditions   |     | Min | Тур | Max  | Unit |
|-------------------|----------------------------------|--|-----|-----|-----|------|------|
| V <sub>DS</sub>   | drain-source voltage             |  |     | -   | -   | 1200 | V    |
| $V_{GS}$          | gate-source voltage              |  | [1] | -10 | -   | 22   | V    |
| I <sub>D</sub>    | drain current                    | T <sub>c</sub> = 25 °C   | [2] | -   | -   | 54   | Α    |
|                   |                                  | T <sub>c</sub> = 100 °C  | [2] | -   | -   | 38   | Α    |
| I <sub>DM</sub>   | peak drain current               | pulsed; t <sub>p</sub> limited by T <sub>j</sub> (max)                 | [3] | -   | -   | 120  | Α    |
| Static characte   | eristics                         |  |     |     |     |      |      |
| R <sub>DSon</sub> | drain-source on-state resistance | $V_{GS} = 18 \text{ V}; I_D = 30 \text{ A}; T_j = 25 ^{\circ}\text{C}$ |     | -   | 40  | 60   | mΩ   |

- [1] Recommended turn off gate voltage is -5 V to 0 V. Recommended turn on gate voltage is 15 V. Do not use with V<sub>GSon</sub> < 13 V.
- [2] Limited by the maximum values of  $T_j$ ,  $R_{th(j-c)}$  and  $R_{DSon}(T_j)$ .
- [3] Designed value (not tested).



# 5. Pinning information

#### **Table 2. Pinning information**

| Pin    | Symbol | Description                       | Simplified outline   | Graphic symbol             |
|--------|--------|-----------------------------------|----------------------|----------------------------|
| 1      | G      | gate                              | mb                   |                            |
| 2      | KS     | kelvin source                     |                      |                            |
| 3 to 7 | S      | source                            |                      | D<br>L                     |
| mb     | D      | mounting base; connected to drain | TO-263-7 (SOT8070-1) | G<br>KS<br>S<br>aaa-036675 |

# 6. Ordering information

### **Table 3. Ordering information**

| Type number   | Package  |   |           |  |  |  |
|---------------|----------|---|-----------|--|--|--|
|               | Name     | Description   | Version   |  |  |  |
| NSF040120D7A1 | TO-263-7 | plastic single-ended surface-mounted package; 7 leads | SOT8070-1 |  |  |  |

# 7. Marking

#### Table 4. Marking codes

| Type number   | Marking code |
|---------------|--------------|
| NSF040120D7A1 | 4012D7A1     |

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol              | Parameter                     | Conditions   |     | Min | Max  | Unit |
|---------------------|-------------------------------|--|-----|-----|------|------|
| V <sub>DS</sub>     | drain-source voltage          |  |     | -   | 1200 | V    |
| V <sub>GS</sub>     | gate-source voltage           |  | [1] | -10 | 22   | V    |
| I <sub>D</sub>      | drain current                 | T <sub>c</sub> = 25 °C                                 | [2] | -   | 54   | Α    |
|                     |                               | T <sub>c</sub> = 100 °C                                | [2] | -   | 38   | Α    |
| I <sub>DM</sub>     | peak drain current            | pulsed; t <sub>p</sub> limited by T <sub>j</sub> (max) | [3] | -   | 120  | Α    |
| P <sub>tot</sub>    | total power dissipation       | T <sub>c</sub> = 25 °C                                 | [2] | -   | 250  | W    |
| Tj                  | junction temperature          |  |     | -55 | 175  | °C   |
| T <sub>stg</sub>    | storage temperature           |  |     | -55 | 150  | °C   |
| T <sub>sld(M)</sub> | peak soldering<br>temperature |  |     | -   | 260  | °C   |
| Source-drai         | n diode                       |  |     |     |      |      |
| Is                  | source current                | T <sub>c</sub> = 25 °C                                 | [2] | -   | 44   | Α    |
| I <sub>SM</sub>     | peak source current           | pulsed; limited by T <sub>j</sub> (max)                | [3] | -   | 90   | Α    |

<sup>[1]</sup> Recommended turn off gate voltage is -5 V to 0 V. Recommended turn on gate voltage is 15 V. Do not use with V<sub>GSon</sub> < 13 V.

### 9. Thermal characteristics

### **Table 6. Thermal characteristics**

| Symbol        | Parameter                                | Conditions | Min | Тур | Max | Unit |
|---------------|--|------------|-----|-----|-----|------|
| $R_{th(j-c)}$ | thermal resistance from junction to case |            | -   | 0.5 | 0.6 | K/W  |

<sup>[2]</sup> Limited by the maximum values of  $T_j$ ,  $R_{th(j-c)}$  and  $R_{DSon}(T_j)$ .

<sup>[3]</sup> Designed value (not tested).

# 10. Characteristics

#### Table 7. Characteristics

| Symbol               | Parameter                         | Conditions   |     | Min  | Тур  | Max | Unit |
|----------------------|-----------------------------------|--|-----|------|------|-----|------|
| Static chara         | acteristics                       |  |     |      |      |     |      |
| V <sub>(BR)DSS</sub> | drain-source<br>breakdown voltage | $I_D = 1 \text{ mA}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$                    |     | 1200 | -    | -   | V    |
| V <sub>GS(th)</sub>  | gate-source threshold             | $I_D = 3 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$                         | [1] | 1.7  | 2.3  | 2.9 | V    |
|                      | voltage                           | I <sub>D</sub> = 15 mA; V <sub>DS</sub> = V <sub>GS</sub> ; T <sub>j</sub> = 25 °C | [1] | -    | 2.77 | -   | V    |
| I <sub>DSS</sub>     | drain leakage current             | V <sub>DS</sub> = 1200 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C            |     | -    | -    | 100 | μΑ   |
| I <sub>GSS</sub>     | gate leakage current              | V <sub>GS</sub> = 22 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C              |     | -    | -    | 100 | nA   |
|                      |                                   | V <sub>GS</sub> = -10 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C             |     | -    | -    | 100 | nA   |
| R <sub>DSon</sub>    | drain-source on-state             | V <sub>GS</sub> = 15 V; I <sub>D</sub> = 30 A; T <sub>j</sub> = 25 °C              |     | -    | 53   | -   | mΩ   |
|                      | resistance                        | $V_{GS}$ = 15 V; $I_D$ = 30 A; $T_j$ = 175 °C                                      |     | -    | 70   | -   | mΩ   |
|                      |                                   | V <sub>GS</sub> = 18 V; I <sub>D</sub> = 30 A; T <sub>j</sub> = 25 °C              |     | -    | 40   | 60  | mΩ   |
|                      |                                   | V <sub>GS</sub> = 18 V; I <sub>D</sub> = 30 A; T <sub>j</sub> = 175 °C             |     | -    | 65   | -   | mΩ   |
| R <sub>G(int)</sub>  | internal gate resistance          | f = 0.5 MHz; T <sub>j</sub> = 25 °C  |     | -    | 2    | -   | Ω    |
| Dynamic ch           | aracteristics                     |  |     |      |      |     |      |
| Q <sub>G(tot)</sub>  | total gate charge                 | $V_{DD}$ = 800 V; $I_{D}$ = 30 A; $V_{GS}$ = -5/+18 V; $T_{j}$ = 25 °C             |     | -    | 81   | -   | nC   |
| $Q_{GS}$             | gate-source charge                |  |     | -    | 35   | -   | nC   |
| $Q_{GD}$             | gate-drain charge                 |  |     | -    | 21   | -   | nC   |
| C <sub>iss</sub>     | input capacitance                 | $V_{DD} = 800 \text{ V}; f = 0.5 \text{ MHz}; V_{GS} = 0 \text{ V};$               |     | -    | 1980 | -   | pF   |
| C <sub>oss</sub>     | output capacitance                | T <sub>j</sub> = 25 °C   |     | -    | 109  | -   | pF   |
| C <sub>rss</sub>     | reverse transfer capacitance      |  |     | -    | 3    | -   | pF   |
| t <sub>d(on)</sub>   | turn-on delay time                | $V_{DD}$ = 800 V; $I_{D}$ = 30 A; $R_{G(ext)}$ = 2.2 $\Omega$ ;                    |     | -    | 14   | -   | ns   |
| t <sub>r</sub>       | rise time                         | $L_L = 82 \mu H; V_{GS} = -5/+18 V; T_j = 25 °C$                                   |     | -    | 13   | -   | ns   |
| t <sub>d(off)</sub>  | turn-off delay time               |  |     | -    | 19   | -   | ns   |
| t <sub>f</sub>       | fall time                         |  |     | -    | 7    | -   | ns   |
| E <sub>on</sub>      | turn-on switching loss            |  |     | -    | 348  | -   | μJ   |
| E <sub>off</sub>     | turn-off switching loss           |  |     | -    | 44   | -   | μJ   |
| Source-drai          | in diode                          |  | •   |      |      |     |      |
| V <sub>SD</sub>      | source-drain voltage              | I <sub>S</sub> = 30 A; V <sub>GS</sub> = -5 V; T <sub>j</sub> = 25 °C              |     | -    | 4.4  | -   | V    |
| t <sub>rr</sub>      | reverse recovery time             | $V_{DD}$ = 800 V; $I_{S}$ = 30 A; $V_{GS}$ = -5 V; $dI_{S}$ /                      |     | -    | 27   | -   | ns   |
| Q <sub>r</sub>       | recovered charge                  | dt = 2908 A/μs; T <sub>j</sub> = 25 °C   |     | -    | 225  | -   | nC   |

<sup>[1]</sup> Measured according to JEP183.

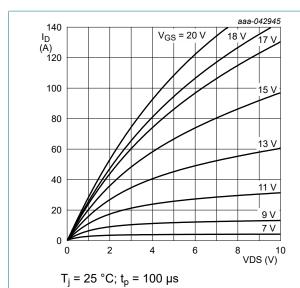


Fig. 1. Output characteristics: drain current as a function of drain-source voltage; typical values

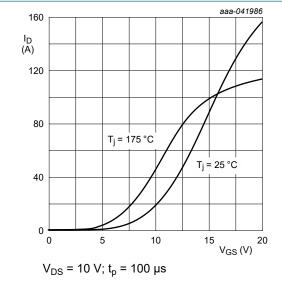


Fig. 3. Transfer characteristics: drain current as a function of gate-source voltage; typical values

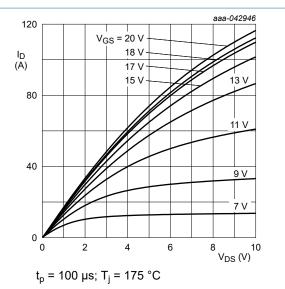


Fig. 2. Output characteristics: drain current as a function of drain-source voltage; typical values

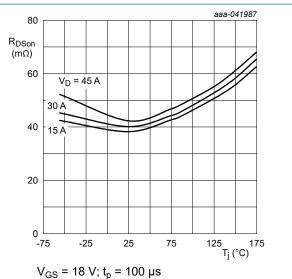


Fig. 4. Drain-source on-state resistance as a function of junction temperature; typical values

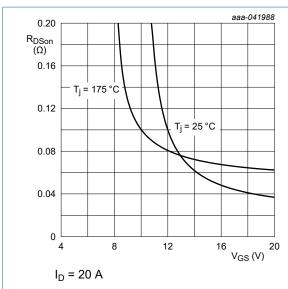


Fig. 5. Drain-source on-state resistance as a function of threshold voltage

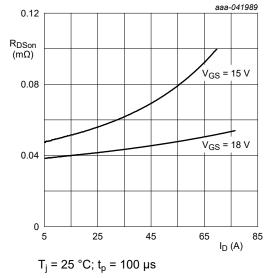


Fig. 6. Drain-source on-state resistance as a function of drain current; typical values

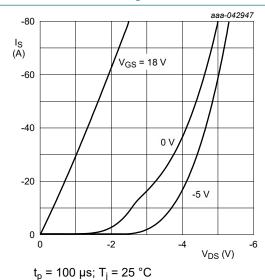


Fig. 7. Source current as a function of sourcedrain voltage; typical values (third quadrant characteristics)

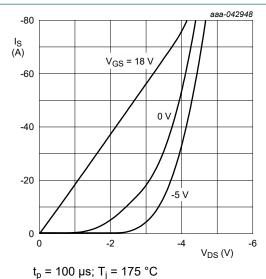


Fig. 8. Source current as a function of sourcedrain voltage; typical values (third quadrant characteristics)

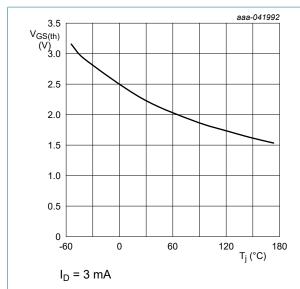
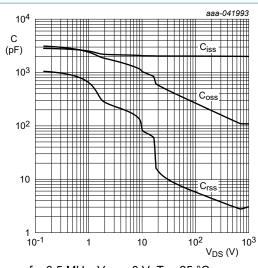


Fig. 9. Gate-source threshold voltage as a function of junction temperature; typical values



 $f = 0.5 \text{ MHz}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$ 

Fig. 10. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

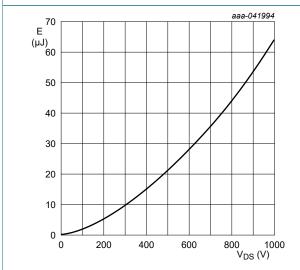
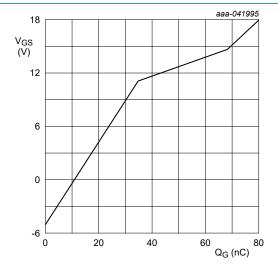


Fig. 11. C<sub>oss</sub> stored energy as a function of drain-souce voltage; typical values



 $V_{DD}$  = 800 V;  $I_{D}$  = 30 A;  $T_{j}$  = 25 °C

Fig. 12. Gate-source voltage as a function of gate charge; typical values

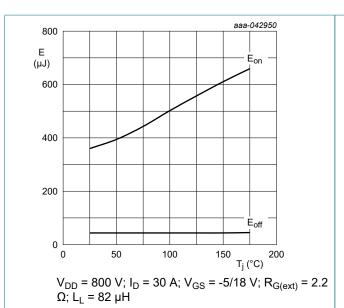


Fig. 13. Switching loss as a function of junction temperature; typical values

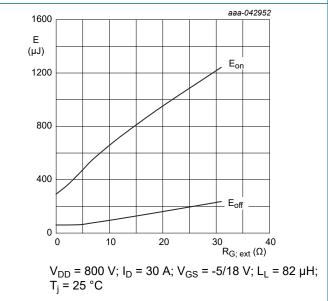


Fig. 15. Switching loss as a function of external gate resistance; typical values

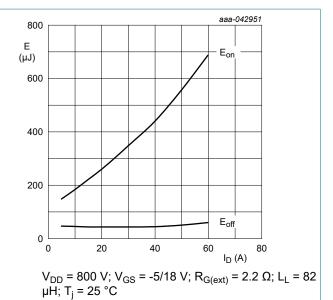


Fig. 14. Switching loss as a function of drain current; typical values

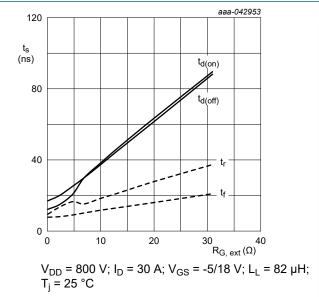
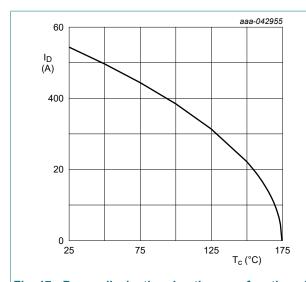
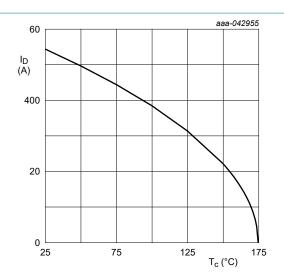


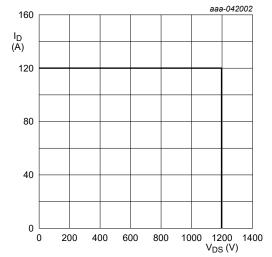
Fig. 16. Switching times as a function of external gate resistance; typical values

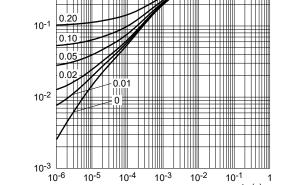




temperature; maximum values

Fig. 17. Power dissipation derating as a function of case Fig. 18. Continuous drain current as a function of case temperature; maximum values





 $V_{GS} = -5/+18 \text{ V}; T_c = 25 \text{ °C}; T_j \le 175 \text{ °C}; \text{ not for }$ linear use

Fig. 20. Transient thermal impedance from junction to case as a function of pulse duration; typical values

### 11. Test information

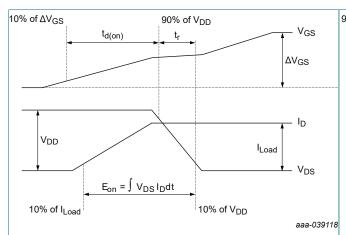


Fig. 21. Definition of switching times and losses during channel turn-on

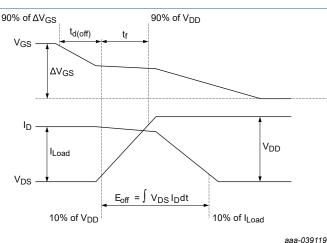


Fig. 22. Definition of switching times and losses during channel turn-off

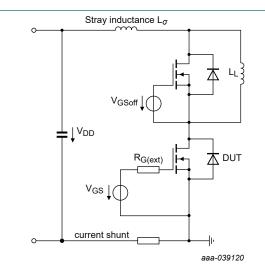


Fig. 23. Test circuit for dynamic characterization of channel and gate charge characteristics

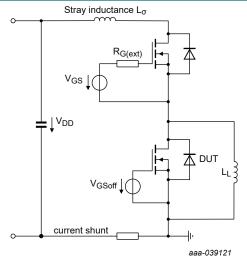


Fig. 24. Test circuit for dynamic characterization of body diode

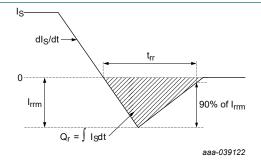


Fig. 25. Definition of dynamic characteristics of body diode

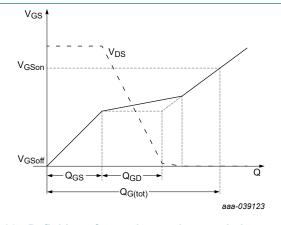
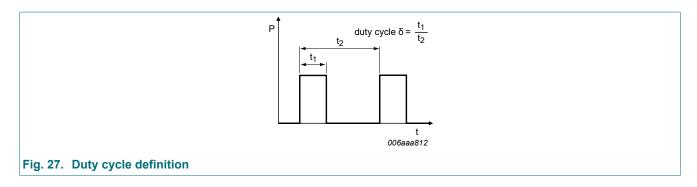


Fig. 26. Definition of gate charge characteristics



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## 12. Package outline

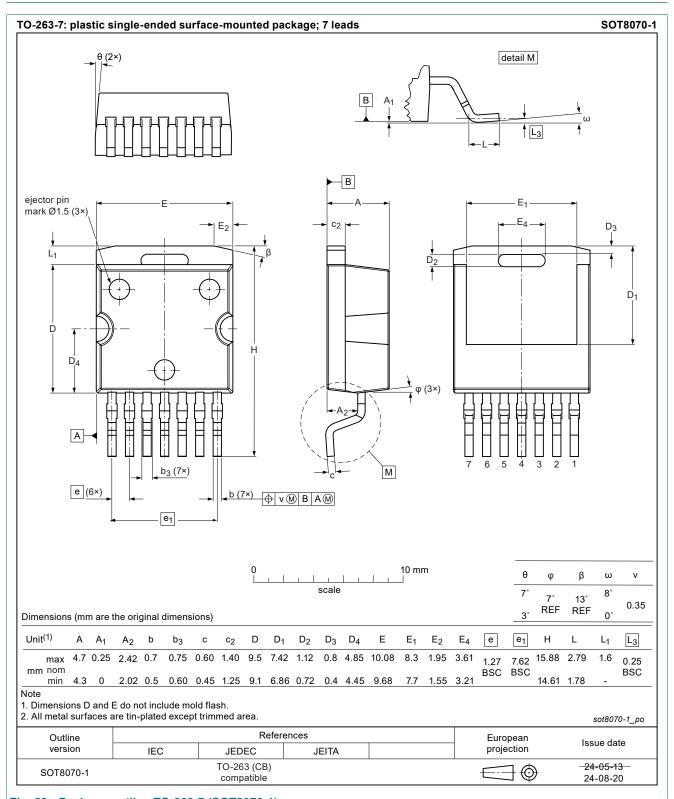
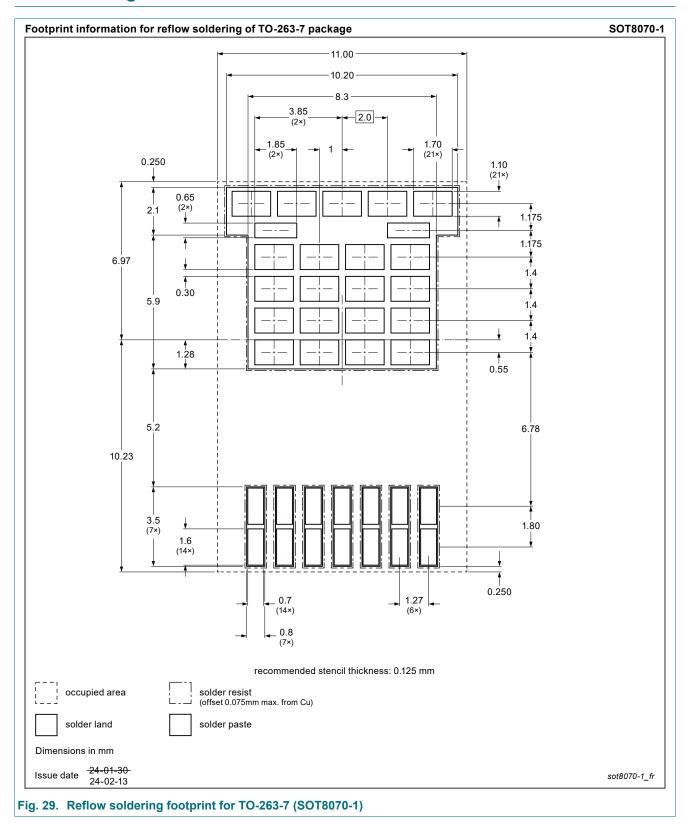


Fig. 28. Package outline TO-263-7 (SOT8070-1)

# 13. Soldering



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# 14. Revision history

#### **Table 8. Revision history**

| Data sheet ID     | Release date           | Data sheet status    | Change notice | Supersedes        |  |  |  |
|-------------------|------------------------|----------------------|---------------|-------------------|--|--|--|
| NSF040120D7A1 v.2 | 20250430               | Product data sheet   | -             | NSF040120D7A1 v.1 |  |  |  |
| Modifications:    | Product status changed |                      |               |                   |  |  |  |
| NSF040120D7A1 v.1 | 20240925               | Objective data sheet | -             | -                 |  |  |  |

## 15. Legal information

#### **Data sheet status**

| Document status [1][2]         | Product<br>status [3] | Definition  |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet   | Development           | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification         | This document contains data from the preliminary specification.                       |
| Product [short]<br>data sheet  | Production            | This document contains the product specification.                                     |

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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